NSN 5961-01-619-1809

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End Application:

C130 acft

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

110.0 collector to base voltage, dc and 110.0 collector to emitter voltage, dc and 55.0 collector to emitter voltage, dc and 4.0 emitter to base voltage, dc

Current Rating Per Characteristic:

20.0 amperes collector current, dc

Power Rating Per Characteristic:

320.0 watts total device dissipation

Special Features:

Description: set of eight 150w pep, 2-30mhz transistors; unit of measure: matched octal; 150 watt (w) npn silicon radio frequency (rf) power transsitor for use in high frequency (hf) broadband linear power amplifiers from 20 to 30mhz

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0